

Predicting Phonon Properties of Defected Systems using the Spectral Energy Density

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5/24/2011



Dielectric Thermal Conductivity

- Dielectric crystal = Electrical Insulator

- Ex: Si, Ge $\vec{q} = -\kappa \nabla T$

- Dielectric Thermal Conductivity:

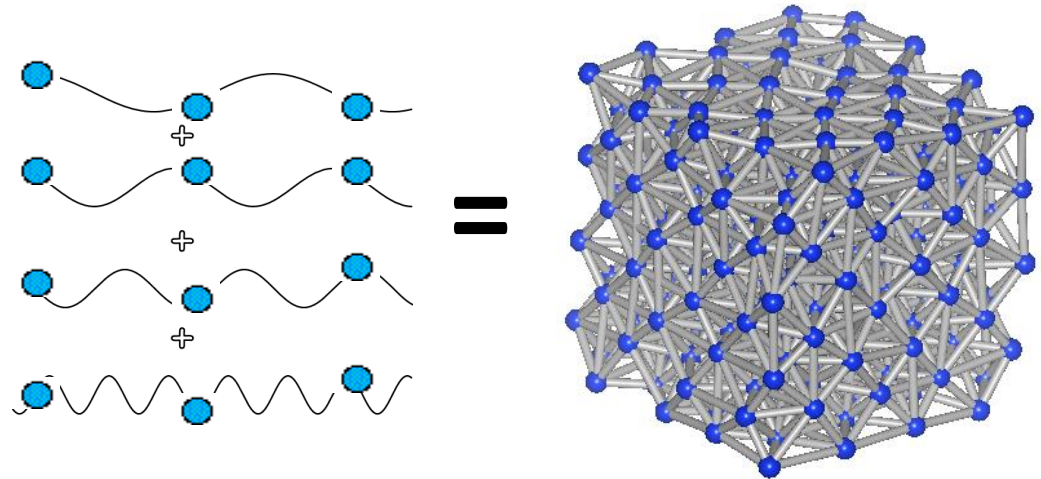
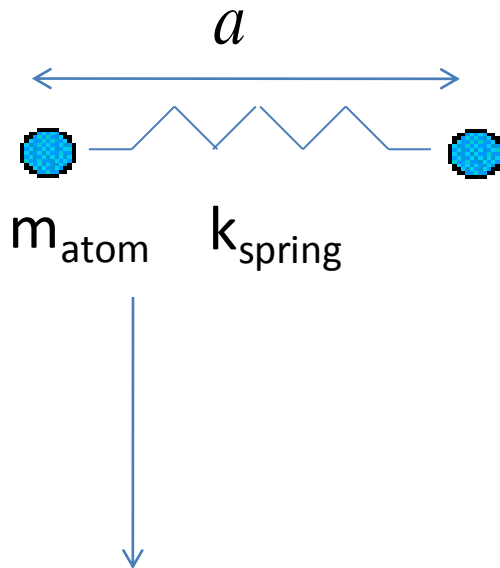
$$K_{total} = K_{phonon} + \cancel{K_{elec}}$$

- **Phonons** are lattice vibrations...

Phonons

Lattice vibrations (**Phonons**) are travelling waves:

$$u(x) \propto e^{i(kx - \omega t)} \longrightarrow v_g$$



Phonons Interact:

- Non-linear springs cause phonons to **interact**.

$$F \propto kx + \epsilon x^3 + \dots$$

Thermal Conductivity Phonon Gas

Kinetic Theory Phonon Gas:

- If system $L \gg \Lambda$:

$$\kappa = \frac{1}{3} \rho c_v v_g \Lambda$$

-Phonons interact: with each other, defects, boundaries, etc.

$$\kappa = \frac{1}{3} \rho c_v v_g \Lambda \quad \longrightarrow \quad \kappa = \frac{1}{V} \sum_i c_v(\omega_i) v_g^2(\omega_i) \tau_i(\omega_i)$$

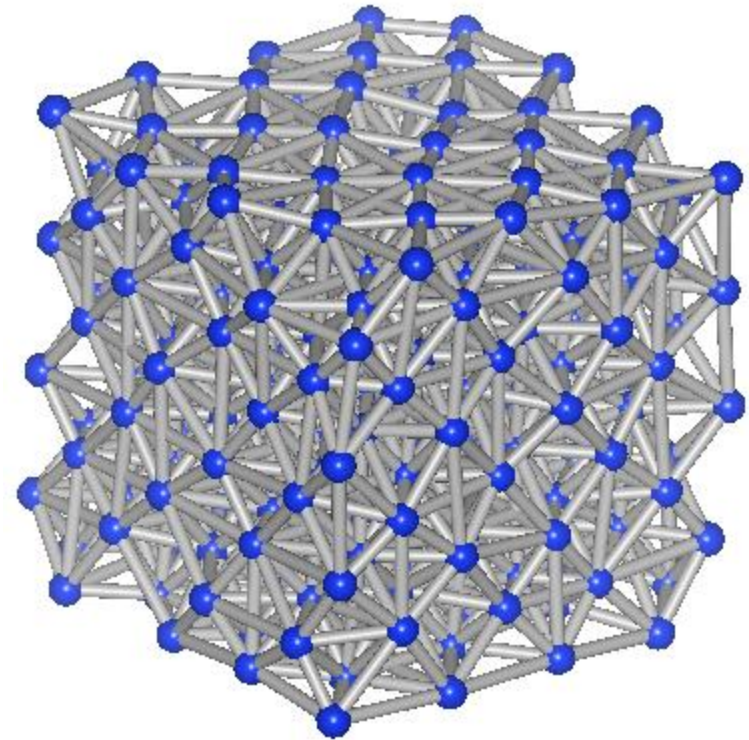
Phonons interact

Molecular Dynamics and Spectral Energy Density

- Molecular Dynamics

- Lennard-Jones:

$$V(r) = 4\varepsilon \left(\left(\frac{\sigma}{r} \right)^{12} - \left(\frac{\sigma}{r} \right)^6 \right)$$



- Spectral Energy Density

- **Frequency, group velocity** and **lifetimes** of phonons from Molecular Dynamics.

$$\vec{r}(t), \vec{p}(t) \longrightarrow \omega_i, \tau_i(\omega_i), v_g(\omega_i)$$



Spectral Energy Density

$$\Phi(\omega, \mathbf{\kappa}) = 2 \sum_v^{3n} \sum_{\alpha, b}^{3, n} \langle T(\mathbf{\kappa}_v^b; \omega) \rangle$$

$$= \frac{1}{4\pi\tau_0 N} \sum_b^n m_b \sum_{\alpha}^3 \left| \int_{-\tau_0}^{\tau_0} \sum_l^N \dot{u}_{\alpha}(\mathbf{r}_0^{(l)}; t) \exp[i\mathbf{\kappa} \cdot \mathbf{r}_0^{(l)} - i\omega t] dt \right|^2$$

Spatial and temporal fourier txn.

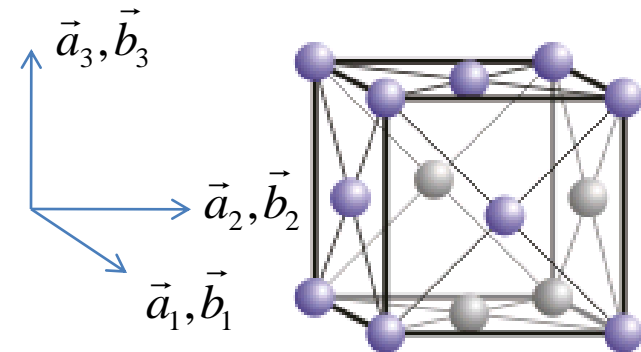
mass

velocity

allowed wavevectors and equil. positions

- No phonon knowledge required *a priori*.
- Can measure:

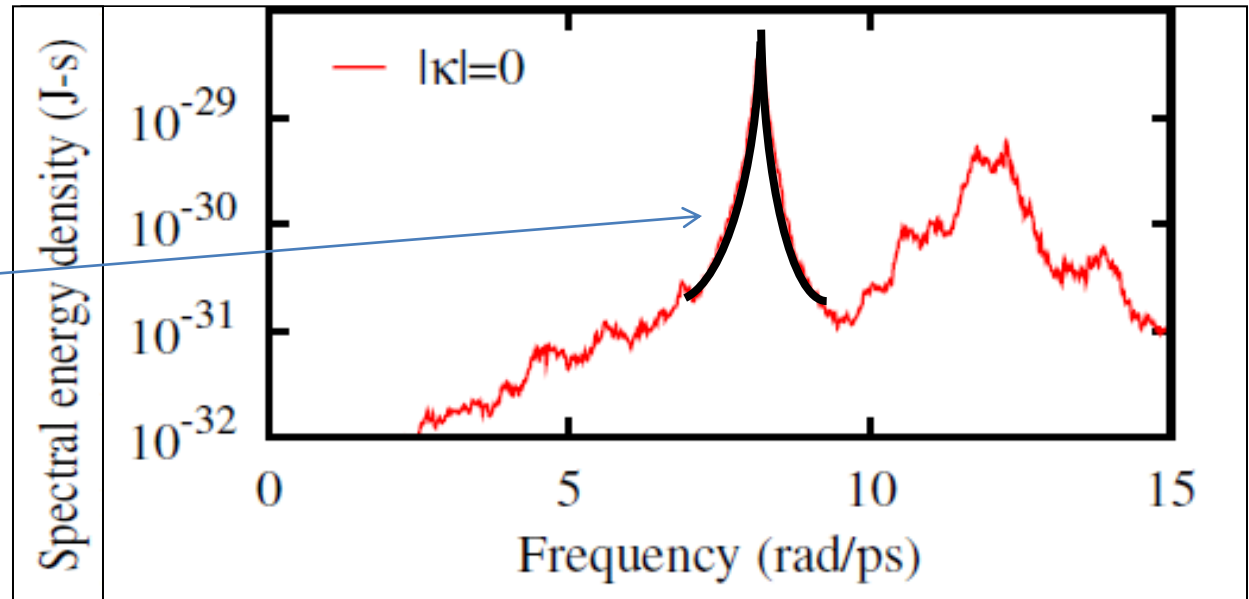
$$\omega_i, \tau_i(\omega_i), v_g(\omega_i)$$



Spectral Energy Density Pure System

- Spectral Energy Density (SED): system energy in frequency and wavevector space.

$$\tau_i(\omega_i) = 1 / 2\Gamma$$



Broad peak = short **lifetime**

$$\omega_i, \tau_i(\omega_i), v_g(\omega_i)$$

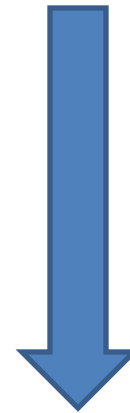
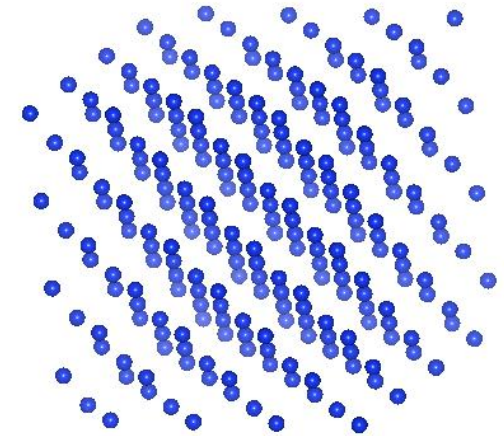
Spectral Energy Density of Defected System

Defect = Disorder = non-periodic

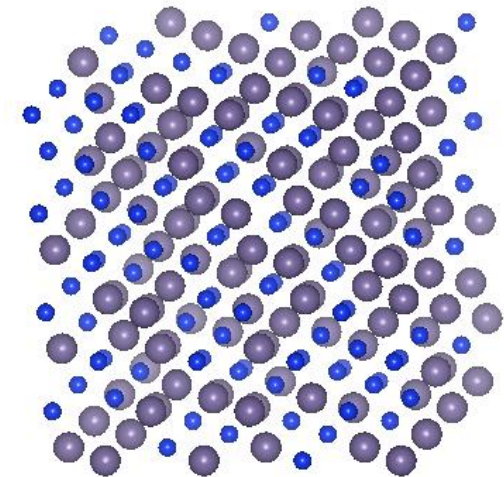
$$m1_{1-x}m2_x$$

$$m1=1.0 \ m2=3.0$$

$$x = 0.0$$



$$x = 0.5$$



Phonon picture still valid?



Bulk Thermal Conductivity Prediction

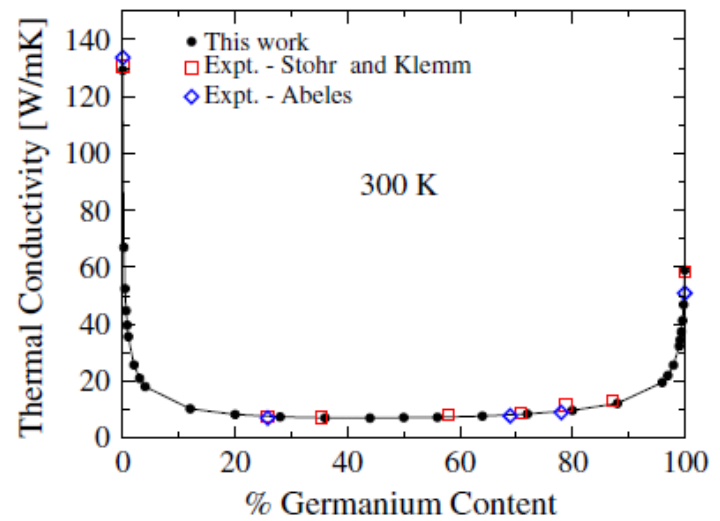
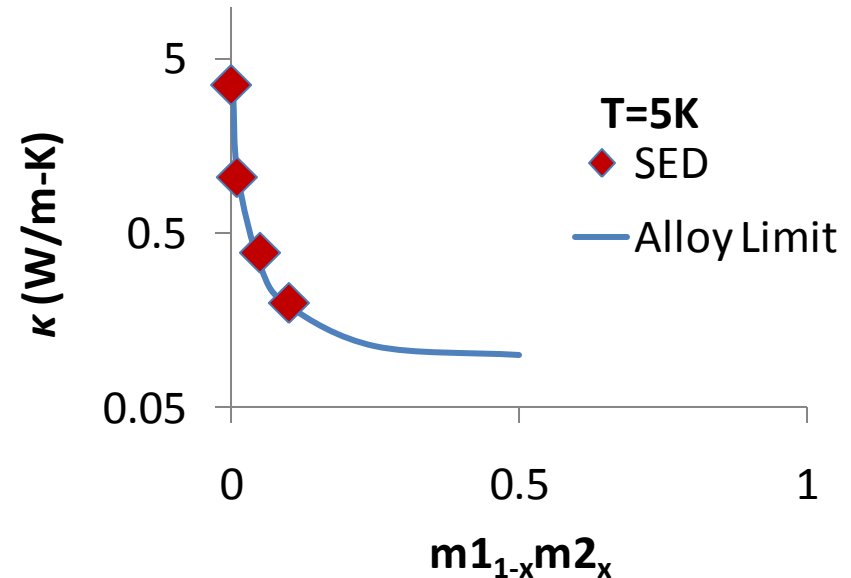
$$\kappa = \frac{1}{V} \sum_i c_v(\omega_i) v_g^2(\omega_i) \tau_i(\omega_i)$$

- Predict thermal conductivity up to $x=0.1$ (**weakly** perturbed)

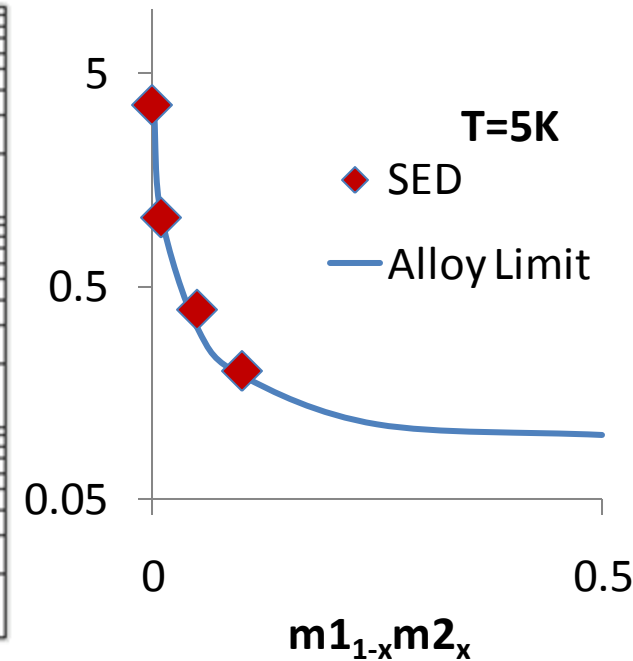
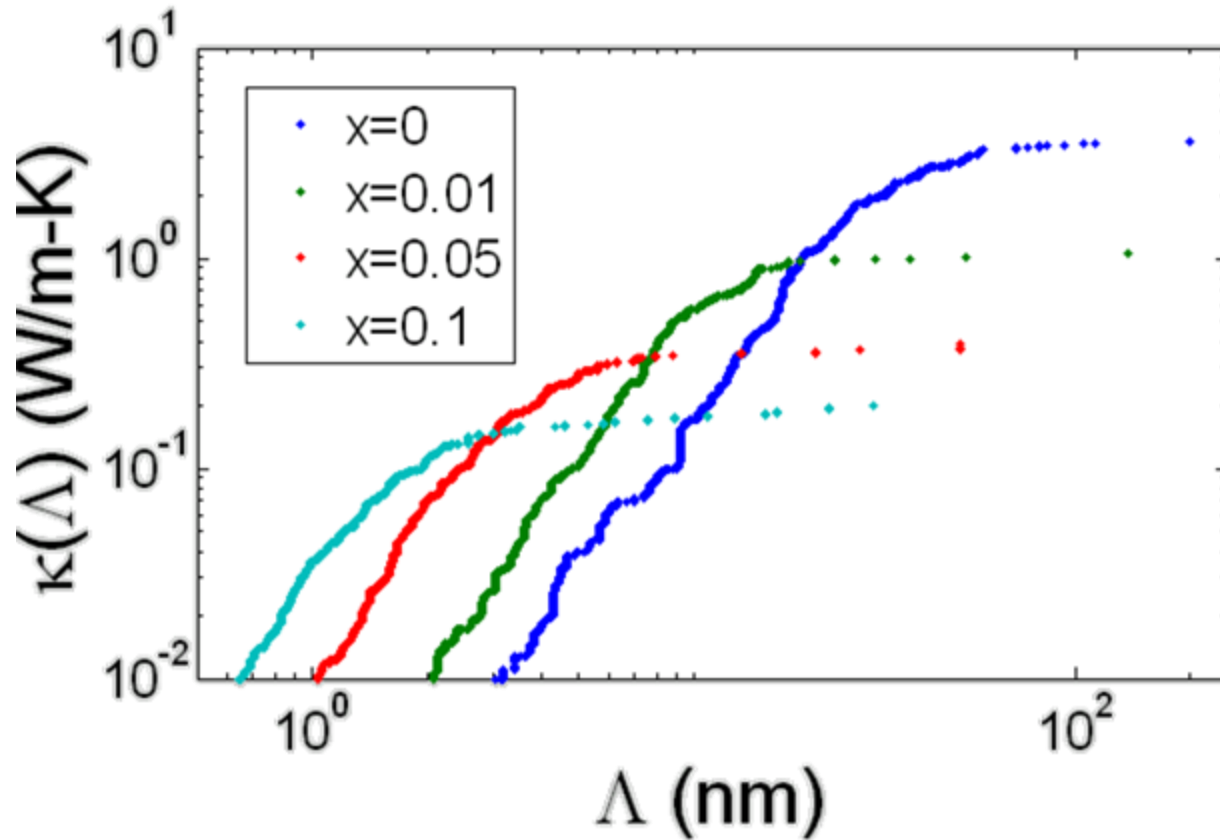
- Typically:

$$0.9\kappa_{\text{alloy}}^{0.1} \approx \kappa_{\text{alloy}}^{0.5}$$

- $m_1/m_2 = 3$ ($m_{\text{Si}}/m_{\text{Ge}} \approx 3$)



Thermal Conductivity of Thin Films



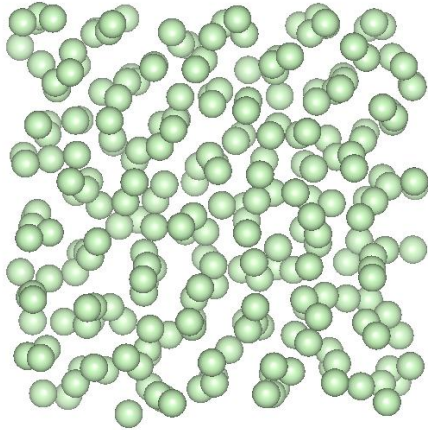
$$\kappa = \frac{1}{V} \sum_i c_v(\omega_i) v_g(\omega_i) \Lambda_i(\omega_i)$$



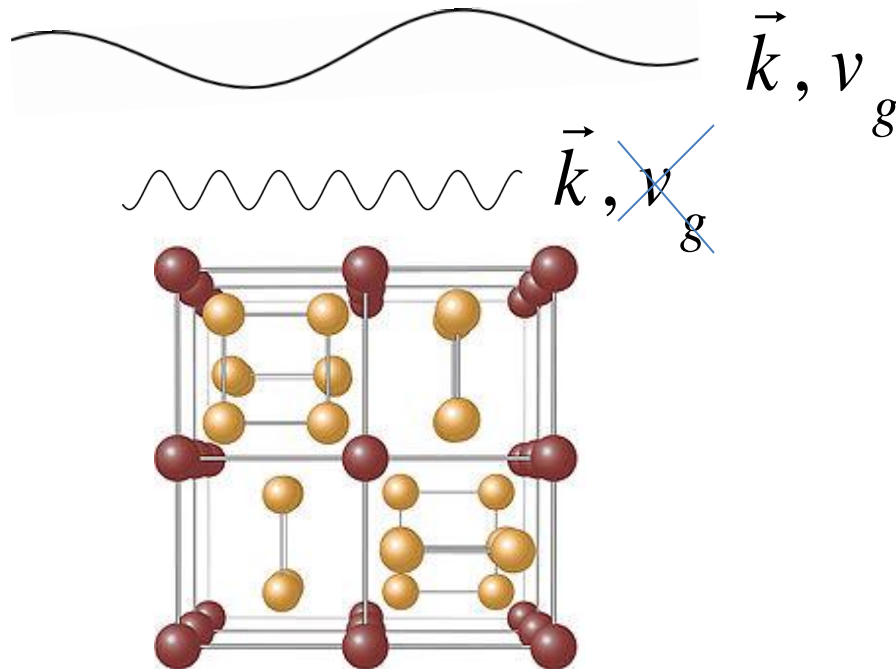
$$L \approx \Lambda$$



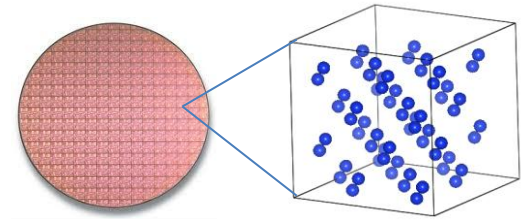
Thermal Conductivity Amorphous (Heavily Disordered) Materials



$$K_{total} = K_{phonon} + K_{disorder}$$

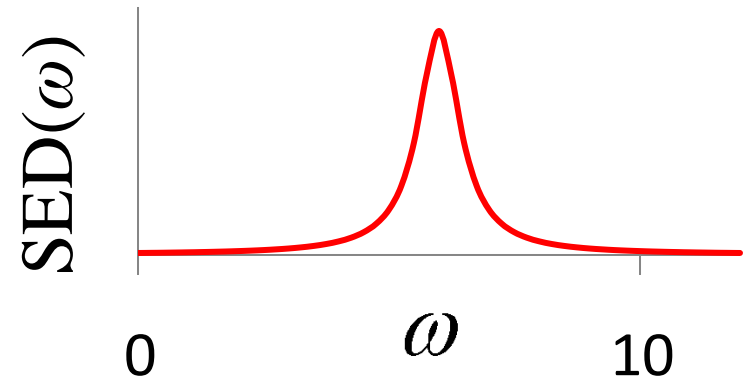


Discussion



$$\vec{q} = -\kappa \nabla T$$

- Dielectric thermal conductivity can be described by **Kinetic Theory** (bulk system).
- **Molecular Dynamics** and **Spectral Energy Density** can measure phonon properties.
- Phonon properties can be predicted for “weakly” perturbed systems, analyzed on mode by mode basis.



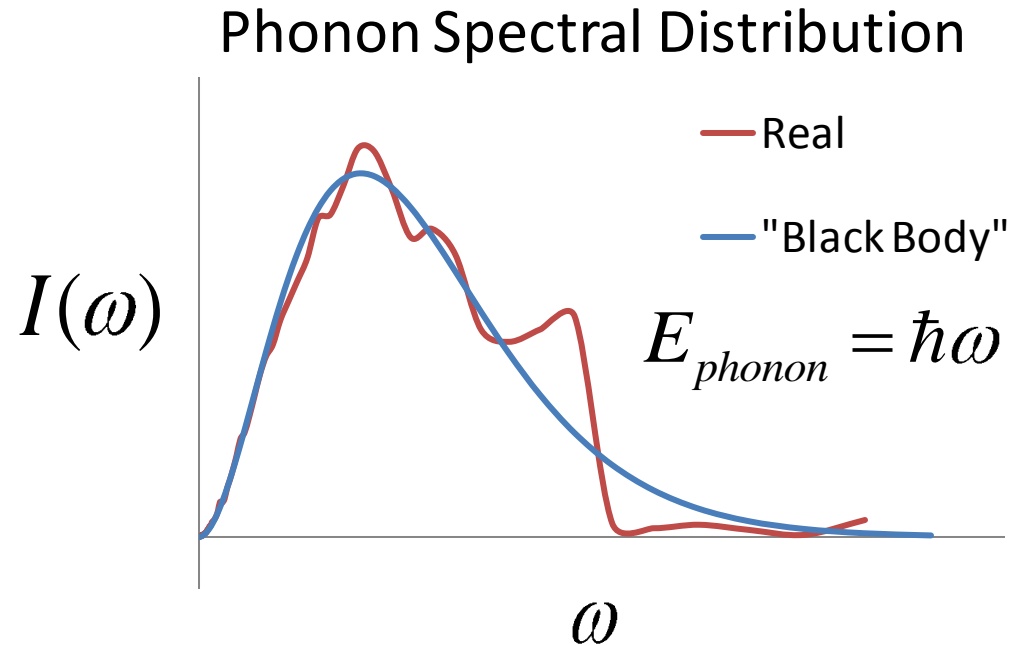
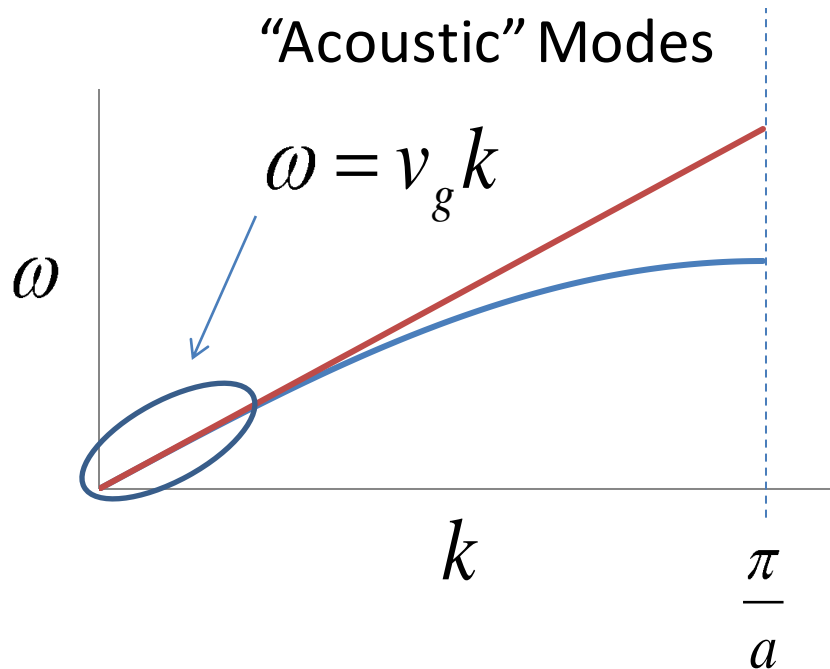
$$\omega_i, \tau_i(\omega_i), v_g(\omega_i)$$



Questions

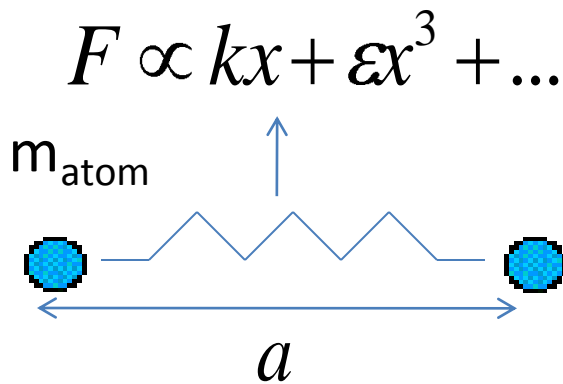


Phonon Gas



Phonons vs. Photons:

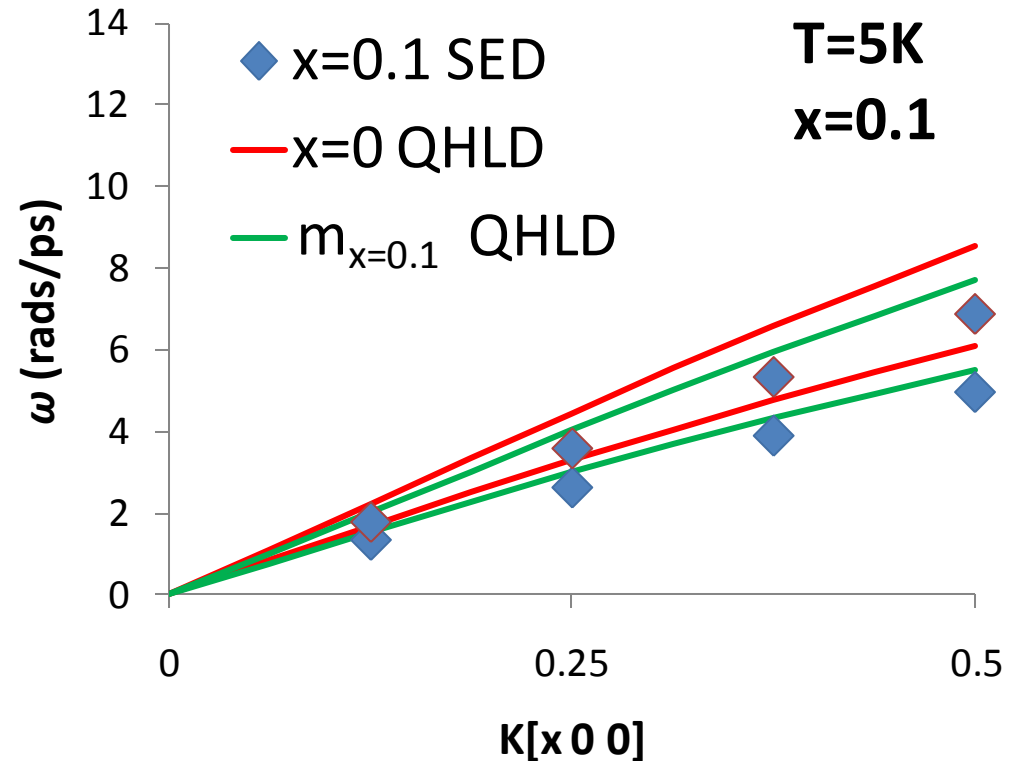
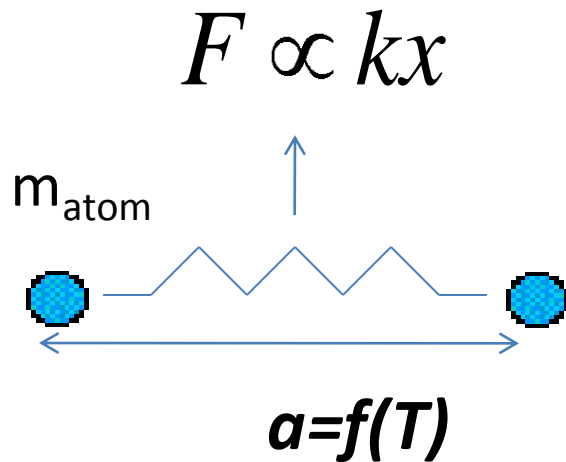
- Non-linear springs
- Phonons interact with each other
- **Interacting Gas...**



Dispersion of Disordered System

- Quasi-Harmonic Lattice

Dynamics:



- Virtual Crystal Approximation:

$$m_{x=0.1} = (0.9m_1 + 0.1m_2) = 1.2$$